

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









905nm Avalanche Photodiode

Product No: MTAPD-06-009/010/011/012

Peak Sensitivity Wavelength: 905nm

The MTAPD-06-xxx is a circular (Φ 230um) 0.04 mm² active area Avalanche Photodiode with optimized sensitivity at 905 nm & housed in a hermetic TO-46 metal can package. It is well suited for applications requiring High Speed & Low Noise in visible-near IR applications.

FFATURES

- >Fast Rise Time
- >Ultra Low Noise
- >Low Capacitance
- >High Gain
- >Optimum Gain M100

>Operating Voltages:

- 120v 160v
- 160v 200v
- Other Voltages Available

APPLICATIONS

- >Optical rangefinders
- > High speed optical communications
- >Medical Equipment
- >Bar Code Readers



Absolute Maximum	Ratings			Pb.
ITEMS	SYMBOL	RATINGS	UNIT	lead-free ROMS
Storage Temperature	Tstg	-55 ~ +125	°C	
Operating Temperature	Topr	-20 ~ +85	°C	
Power Dissipation	Pd	1	mW	
Forward Current	If	1	mA	
Operating Voltage	Vop	0.95 x Vbr	V	
Lead Soldering Temperature *1	Tls	260	°C	

*1: Time 10 Sec max

ITEMS	SYMBOL	CONDITIONS	MIN.	TYP	MAX.	UNIT
Spectral Response	λ			400 - 1100		nm
Active Area				Diameter 230		um
Responsivity	Re	λ=905nm, oe=1uW, M=100	50	55		A/W
Rise Time	t_R	f=1MHz, RL=50Ω, λ =905nm		0.6		ns
Dark Current	I_{D}	M=100	0.1	0.2	1.0	nA
Capacitance	Cj	M=100, f=1MHz		1		pF
Optimal Gain	М			100		
Breakdown Voltage	Vbr	IR=2uA	80		200	V
Temperature Coefficient		Tc=-40°C - 85°C		0.9		V/°C

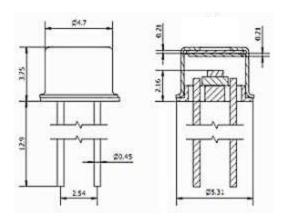
2016-11-04



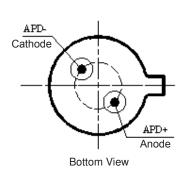
905nm Avalanche Photodiode

Product No: MTAPD-06-009/010/011/012

TO-46 Package Dimensions (2 Pin)

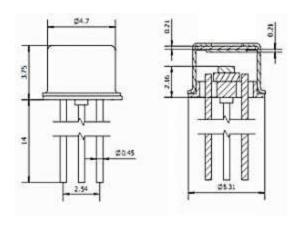


MTAPD-06-009 Vbr=120-160V MTAPD-06-010 Vbr=160-200V



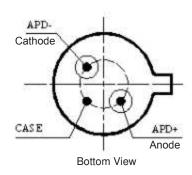
Unit: mm, Tolerance: ±0.2

TO-46 Package Dimensions (3 Pin)

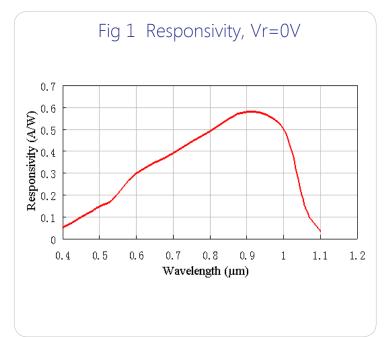


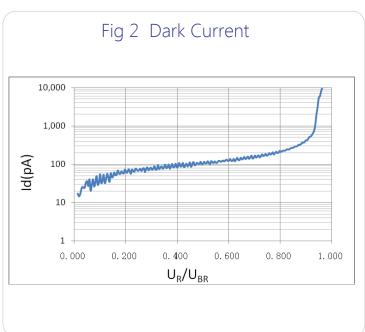
Unit: mm, Tolerance: ±0.2

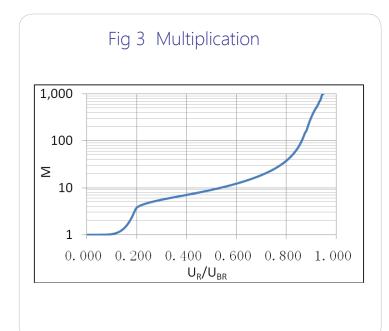
MTAPD-06-011 Vbr=120-160V MTAPD-06-012 Vbr=160-200V

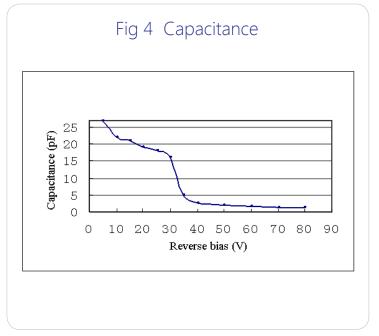


Product No: MTAPD-06-009/010/011/012







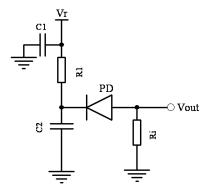




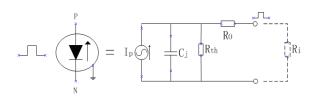
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Applications Diagram



Equivalent Circuit Diagram



Notes: C1 - Filter capacitor, filter noise from Vr.

C2 - bypass capacitor, the loop to ground for AC signal.

R1 - current-limiting resistor, protect APD from higher voltage.

Ri - sampling resistor, convert the current signal into a voltage signal.

ESD S

The information contained herein is subject to change without notice.

2016-11-04